

Small Signal Fast Switching Diode

General Description

General-purpose switching diodes, fabricated in planar technology, and packaged in small SOD-123 surface mounted device (SMD) packages.



SOD-123



Features and Benefits

- Silicon epitaxial planar diode
- High switching speed: $t_{rr} \leq 4\text{ns}$
- Low forward drop voltage and low leakage current
- “Green” device and RoHS compliant device
- Available in full lead (Pb)-free device

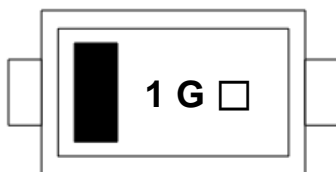
Applications

- Ultra high speed switching application

Ordering Information

Part Number	Marking Code	Package	Packaging
SDS4148G	1G □	SOD-123	Tape & Reel

Marking Information

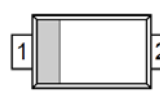
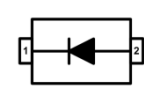


1 G = Specific Device Code

□ = Year & Week Code Marking

■ = Color band denote cathode

Pinning Information

Pin	Description	Simplified Outline	Graphic Symbol
1	Cathode		
2	Anode		

Absolute Maximum Ratings (T_{amb}=25°C, Unless otherwise specified)

Characteristic	Symbol	Ratings	Unit
Maximum repetitive peak reverse voltage	V _{RM}	100	V
Continuous reverse voltage	V _R	75	V
Maximum average forward rectified current	I _O	150	mA
Forward current (DC)	I _F	150	mA
Maximum repetitive peak forward current	I _{FM}	300	mA
Non-repetitive peak forward surge current(t=10ms)	I _{FSM}	2	A
Power dissipation ¹⁾	P _D	500	mW

¹⁾ Device mounted on FR-4 board with recommended pad layout.

Thermal Characteristics (T_{amb}=25°C, Unless otherwise specified)

Characteristic	Symbol	Ratings	Unit
Thermal resistance, junction to ambient ¹⁾	R _{th(j-a)}	250	°C/W
Operating junction temperature	T _j	150	°C
Storage temperature range	T _{stg}	-55 ~ 150	°C

¹⁾ Device mounted on FR-4 board with recommended pad layout.

Electrical Characteristics (T_{amb}=25°C, Unless otherwise specified)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Reverse breakdown voltage	V _{BR}	I _R =100uA	100	-	-	V
Forward voltage ²⁾	V _F	I _F =50mA	-	0.85	1.0	V
Reverse leakage current ³⁾	I _{R(1)}	V _R =20V	-	-	25	nA
	I _{R(2)}	V _R =20V, T _a =150°C	-	-	50	uA
	I _{R(3)}	V _R =75V	-	-	5	uA
Total capacitance	C _T	V _R =0V, f=1MHz	-	-	4.0	pF
Reverse recovery time	t _{rr}	I _F =10mA, V _R =6V I _{rr} =0.1xI _R , R _L =100Ω	-	-	4.0	ns

²⁾ Pulse test: t_p≤380μs, Duty cycle≤2%

³⁾ Pulse test: t_p≤5ms, Duty cycle≤2%

Rating and Characteristic Curves

Fig. 1) Typical Forward Characteristics

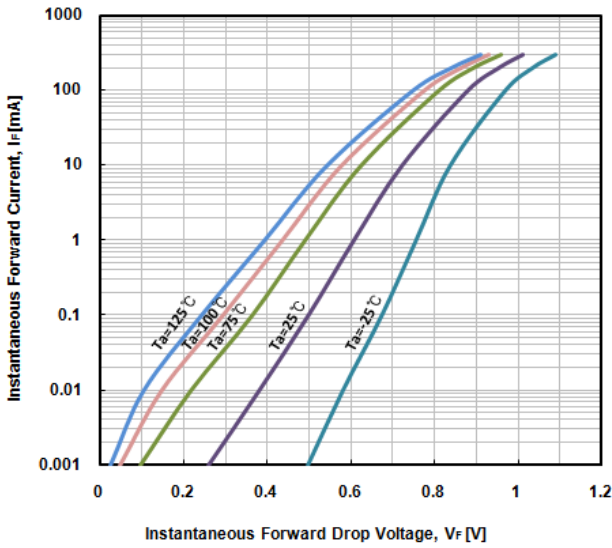


Fig. 2) Typical Reverse Characteristics

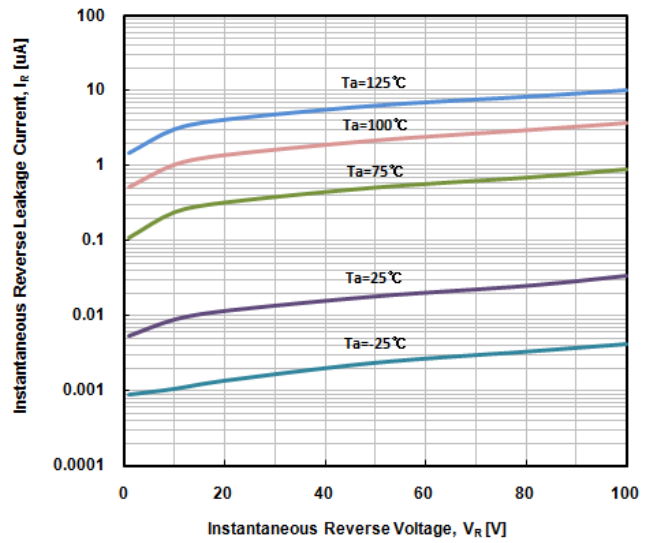


Fig. 3) Typical Total Capacitance Characteristics

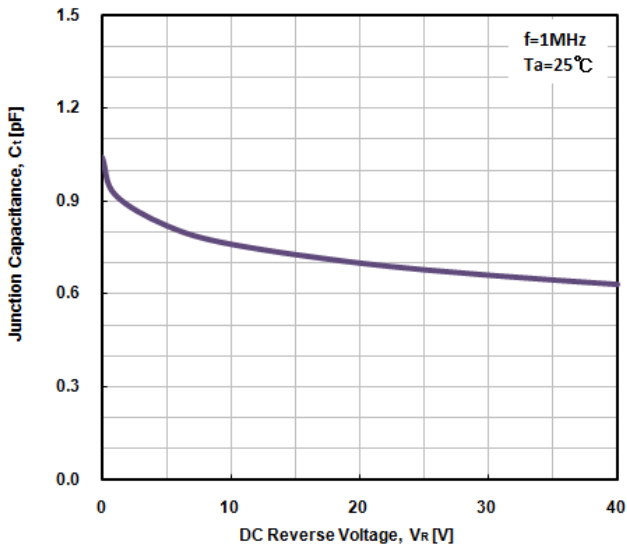


Fig. 4) Reverse Recovery Time vs. Forward Current

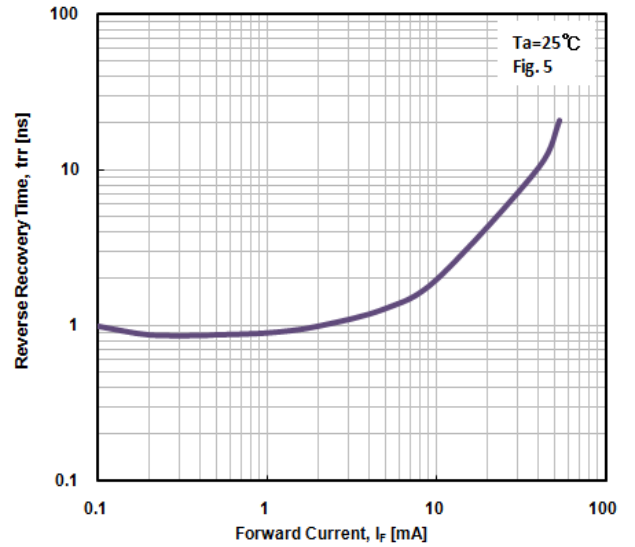
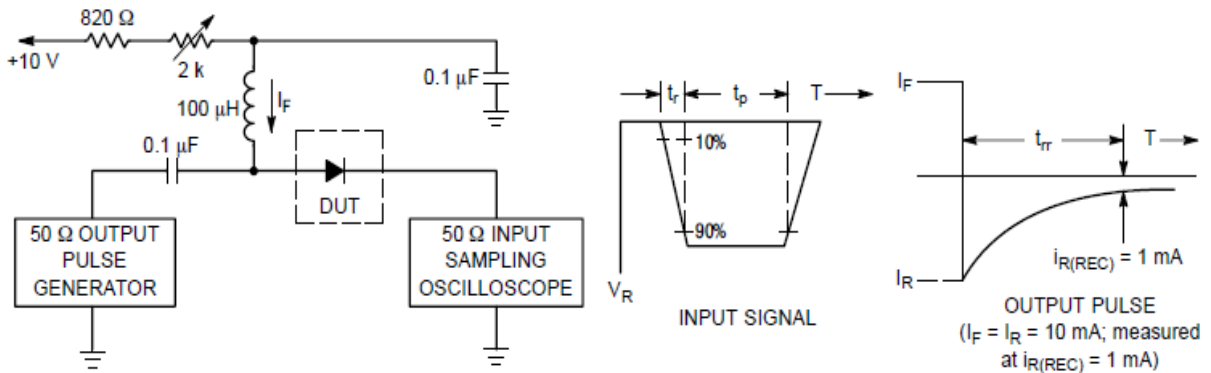
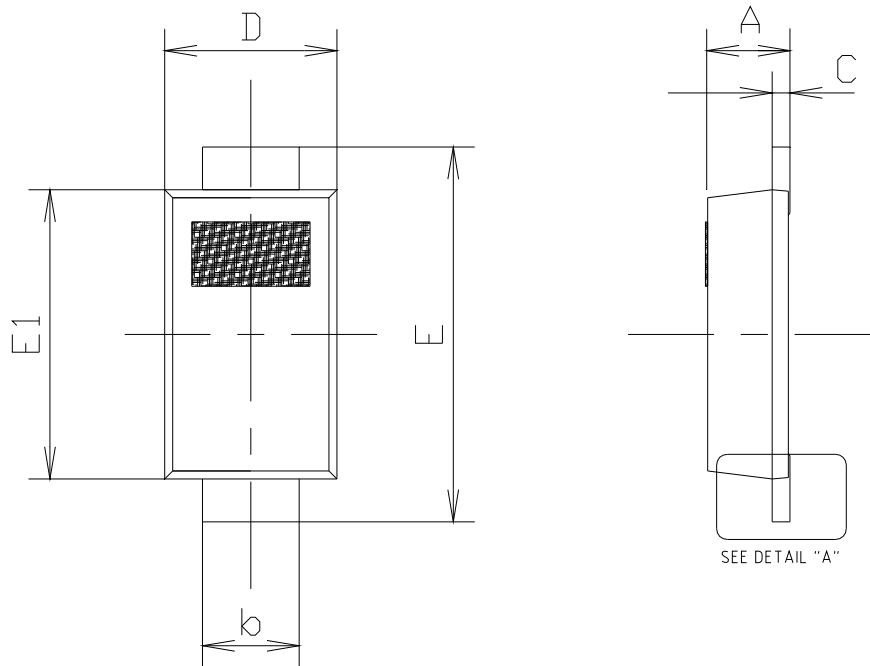


Fig. 5) Reverse recovery time equivalent test circuit

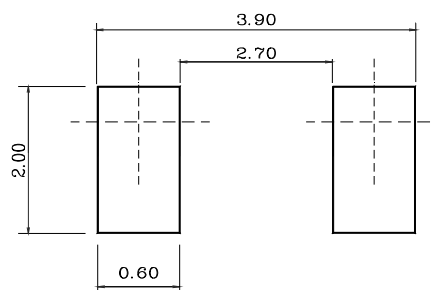


Package Outline Dimensions



SYMBOL	MILLIMETERS			NOTE
	MINIMUM	NOMINAL	MAXIMUM	
A	0.80	0.90	1.00	
b	0.50	0.60	0.70	
c	0.12	0.16	0.20	
D	1.50	1.60	1.70	
E	3.30	3.50	3.70	
E1	2.50	2.60	2.70	

※ Recommend PCB solder land (Unit : mm)



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